## TOSHIBA

# Low Voltage MOSFETs

### **Highest Efficiency at Light Loads**

U-MOS VIII-H and IX are high-efficiency Low Voltage (LV) MOSFET series, specifically designed for use in the secondary side of AC-DC power supplies for adapters, servers etc. as well as DC-DC power supplies for communication equipment, servers and data center. U-MOS IX is also suitable for motor drives, UPS and machine tools. The U-MOS VIII-H and IX series provide higher efficiency at light loads while providing the same efficiency as competitors' devices at heavy loads. This technology is specified up to 175°C for use in higher temperature applications.

#### Applications

- Power Supplies
- ServersAdapters
- UPS
  - Machine Tools
- Battery PacksWelding

- Industry Automation
- **Benefits Features** Advantages • Latest Gen-8 and Gen-9 trench MOS Attractive cost effects • Applicable in various power apps. Significantly better trade-offs process Lower system costs due to fast between on-resistance (R<sub>DS(ON)</sub>) and • Improved energy efficiency switching & smaller form factor input capacitance (C<sub>iss</sub>). categories High avalanche ruggedness. Low service costs based on Reduced electromagnetic radiation. Dual side cooling increased lifetime (cooler system) to reduce costs of operation failures • Highest performance in on- Same efficiency as competitors' devices at heavy loads and higher • Flexible system costs by cost resistance per die area (RON · A) efficiency at light loads variations related to product - Wide range of  $V_{\text{DSS}}$  (30V-250V) and construction (topology)  $R_{DS(ON)}$  values down to 0.6m $\Omega$ • Reduction of thermal resistance by approx. 50% resulting in higher load Smart performance increases capability and reliability Improved end product quality • Ideal for applications that require • Improved end product reliability higher efficiency, smaller size etc. · Increased demand and market Meets the requirements of various share applications

### Dual side cooling

Using the new DSOP dual-side cooling package shows the same footprint as the SOP-Advanced. Due to the strongly reduced thermal resistance, the maximum load can be increased considerably. Alternatively the MOSFET temperature can be reduced to increase long term reliability.







	P					NEW		
V <sub>DSS</sub>	In mO	TO-220515	TO.220	D2-PAK	SOP Advance	DSOP Advance	TSON Advance	DPAK
(V)	111 11152	10-220515	10-220	(TO-263)	5x6mm	5x6mm	3x3mm	DPAK
			Part -	Paum	- 1	- 1-		
		5	77		Contraction and and and and and and and and and an	DL		
	10-20	///	1//	1.24	ILLUTIONSINF		TPN11003NL	1
30							TPN8R903NL	
	5 10				TPH8R903NL		TPN6R003NL	
	5-10				TPH6R003NL		TPN6R303NC	
							TPN5R203PL**	
	3-5				TPH4R003NL		TPN4R203NC	
					TPH3R203NL		TPN4R303NL	
							TPN2R203NC	
	1-3				TPH2R003PL **			
					TPH1R403NI		TPN2R903PI **	
					TPHR9003NL		11112100012	
	<1				TPHR9203PL**	TPWR8503NL	TPN1R603PL**	
					TPHR6503PL**	TPWR6003PL""		
40	F 10				TPH7R204PL**			
	5-10				TPH6R004PL**		TI NINJUHI L	
	3-5	TK3R1A04PL**	TK3R1E04PL**		TPH3R704PL**		TPN3R704PL**	TK3R1P04PL**
				TK1R5R04PB **	TPH2R104PL**			
	<3			TK1R4F04PB* **	TPH1R204PB**		TPN2R304PL**	
					TPH1R204PL**			
	<1			TKR74F04PB* **	TPHR8504PL**	TPWR8004PL**	TDN2200CNU	
60		TKOAAGNI					TPN22006NH	
	10-30				TPH14006NH			
		1140/00111	IN40L00N1		TITITOOONL		TPNI1006PL **	
					TPH9R506PI **		TH NI LOUGH E	
	6-10	TK58A06N1	TK58E06N1		TPH7R506NH TPN7	TPN7R506NH	TK6R7P06PL**	
		TK8R2A06PL**	TK8R2E06PL**		TPH7R006PL**		TPN7R006PL**	
	2.0	TK5R3A06PL**	TK5R1E06PL**		TPH5R906NH			
	3-0	TK4R3A06PL**	TK4R3E06PL**		TPH3R506PL**		I PIN4KOUOPL	IN4R4PUOPL
	1-3	TK100A06N1	TK100E06N1		TPH2R306NH			
					TPH2R506PL**	TPW1R306PI **		
	10	TK3R3A06PL**	111200200112		TPH1R306PL**			
75	1.0				TPHIR306P1**	TOWODECONUL		
80	1-3 20.50				TPH2R608NH	TPW2R508NH		
	10-20	TK35408N1	TK35E08N1		TPH12008NH		TPN13008NH	
	5-10	TK46A08N1	TK46F08N1		TPH8R008NH		1111130001111	
	0 10	TK72A08N1	TK72E08N1					
	3-5	TK100A08N1	TK100E08N1		TPH4R008NH	TPW4R008NH		
100	30-50						TPN3300ANH	
	10.30	TK22A10N1	TK22E10N1				TPN1600ANH	TK11001001 **
	10-30	TK110A10PL	TK110E10PL		11 111400AN11		TPN1200APL**	
		TK34A10N1	TK34E10N1					
	5-10	1K40A10N1	IK40E10N1	TK60R10N1L	TPH8R80ANH			TK7R7P10PL**
					TPH6R3UANL			
			IN6R4E10PL					
		TK4R1A10PI	TK65E10N1		TPH4R50ANH	TPW4R50ANH		
	3-5	TK100A10N1	TK3R9E10PL	TK65G10N1	TPH4R10ANI	TPW3R70API **		
		TK3R2A10PL	TK100E10N1		TPH3R70APL**			
	<3		TK2R9E10PL	TK160F10N1L*				
120	10-20	TK32A12N1	TK32E12N1					
	5-10	TK42A12N1	TK42E12N1					
	J-10	TK56A12N1	TK56E12N1					
	3-5	TK72A12N1	TK72E12N1		TDUESSAG		TONICOCO	
150	50-100				TPH5900CNH		TPN5900CNH	
150	20-50				TPH3300CNH			
	100.200				TDH1110ENU	TPW1500CNH		
200	50-100						IFINITIUEINH	
200	20-50				TPH2900ENH	TPW2900ENH		
	200-300				TPH2010FNH		TPN2010FNH	
250	100-200				TPH1110FNH			
	50-100				TPH5200FNH	TPW5200FNH		
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\* TO-220SM(W) package; \*\* U-MOS IX technology; New Product

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